



17μA Max, Dual/Quad, Single-Supply, Precision Op Amps

MAX478

General Description

The MAX478 and MAX479 are dual and quad micro-power, precision op amps available in 8-pin and 14-pin DIP and small-outline packages, respectively. Both devices feature an extremely low, 17 μA max supply current per op amp, 70μV max offset voltage, 2.2μV/°C max offset voltage drift (0.5μV/°C typ), and 250pA max input offset current.

The MAX478 and MAX479 operate from a single supply. The input voltage range includes ground, and the output swings to within a few millivolts of ground, which eliminates pull-down resistors and saves power.

Both devices are optimized for single 3V and 5V supply operation, with guaranteed specifications at each supply voltage. Specifications for ±15V operation are also provided.

Applications

Battery- or Solar-Powered Systems:

Portable Instrumentation
Remote Sensor Amplifier
Satellite Circuitry

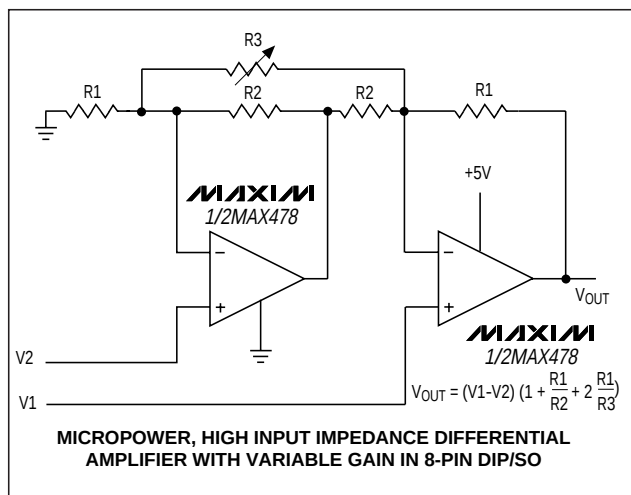
Micropower Sample-and-Hold

Thermocouple Amplifier

Micropower Filters

Single Lithium Cell Powered Systems

Typical Operating Circuit



Features

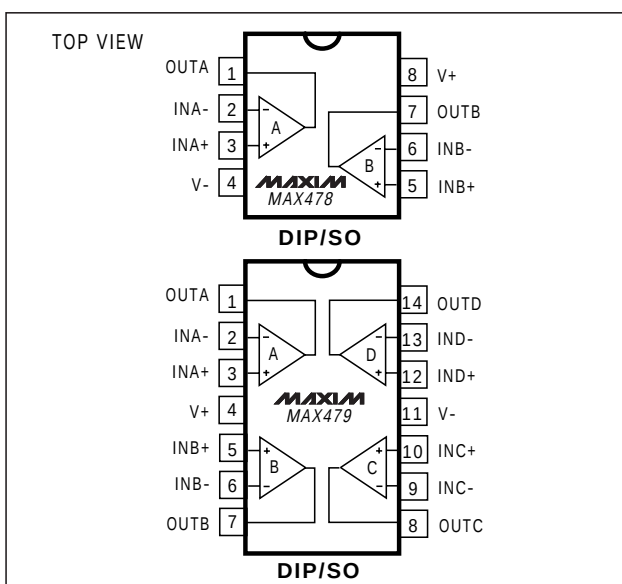
- ♦ 17μA Max Supply Current (MAX478A/MAX479A)
- ♦ 70μV Max Offset Voltage (MAX478A)
- ♦ Single-Supply Operation:
Input Voltage Range Includes Ground
Output Swings to Ground While Sinking Current
No Pull-Down Resistors Required
- ♦ Dual Op Amp in 8-Pin DIP/SO Package (MAX478)
Quad Op Amp in 14-Pin DIP/SO Package (MAX479)
- ♦ 250pA Max Input Offset Current (MAX478A/MAX479A)
- ♦ 0.5μV/°C Offset-Voltage Drift
- ♦ Output Sources and Sinks 5mA Load Current

Ordering Information

PART	TEMP. RANGE	PIN-PACKAGE
MAX478ACPA	0°C to +70°C	8 Plastic DIP
MAX478CPA	0°C to +70°C	8 Plastic DIP
MAX478CSA	0°C to +70°C	8 SO
MAX478C/D	0°C to +70°C	Dice*
MAX478EPA	-40°C to +85°C	8 Plastic DIP
MAX478ESA	-40°C to +85°C	8 SO
MAX479ACPD	0°C to +70°C	14 Plastic DIP
MAX479CPD	0°C to +70°C	14 Plastic DIP
MAX479CSD	0°C to +70°C	14 SO
MAX479EPD	-40°C to +85°C	14 Plastic DIP
MAX479ESD	-40°C to +85°C	14 SO

* Dice are specified at $T_A = +25^\circ\text{C}$, DC parameters only.

Pin Configurations



Maxim Integrated Products 1

For free samples & the latest literature: <http://www.maxim-ic.com>, or phone 1-800-998-8800.
For small orders, phone 1-800-835-8769.

www.datasheetall.com

17 μ A Max, Dual/Quad, Single-Supply, Precision Op Amps

ABSOLUTE MAXIMUM RATINGS

Supply Voltage	±22V
Differential Input Voltage	±30V
Input Voltage	Equal to Positive Supply Voltage 5V Below Negative Supply Voltage
Output Short-Circuit Duration	Continuous
Continuous Power Dissipation (T _A = +70°C):	
8-Pin Plastic DIP (derate 9.09mW/°C above +70°C)	727mW
14-Pin Plastic DIP (derate 10.00mW/°C above +70°C) ..	800mW
14-Pin Wide SO (derate 9.52mW/°C above +70°C) ...	762mW

Operating Temperature Ranges:

MAX47_ACP_/C_.....	0°C to +70°C
MAX47_E_.....	-40°C to +85°C
Storage Temperature Range	-65°C to +150°C
Lead Temperature (soldering, 10sec).....	+300°C

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

ELECTRICAL CHARACTERISTICS: 5V

($V_S = 5V, 0V, V_{CM} = 0.1V, V_O = 1.4V, T_A = +25^\circ C$, unless otherwise noted.)

PARAMETER	SYMBOL	CONDITIONS	MAX478AC MAX479AC			MAX478C/E MAX479C/E			UNITS
			MIN	TYP	MAX	MIN	TYP	MAX	
Input Offset Voltage	V _{OS}	MAX478ACP/CP/EP	30	70		40	120	μV	
		MAX479ACP/CP/EP	35	100		40	150		
		MAX478CS/ES				80	180		
		MAX479CS/ES				90	250		
Long-Term Input Offset-Voltage Stability	$\frac{\Delta V_{OS}}{\Delta \text{Time}}$		0.5			0.6		μV/Mo.	
Input Offset Current	I _{OS}		0.05	0.25		0.05	0.35	nA	
Input Bias Current	I _B		3	5		3	6	nA	
Input Noise Voltage	e _n	0.1Hz to 10Hz (Note 1)	0.9	2.0		0.9		μV _{p-p}	
Input Noise Voltage Density		f _O = 10Hz (Note 1)	50	75		50		nV/√Hz	
		f _O = 1000Hz (Note 1)	49	65		49			
Input Noise Current	i _n	0.1Hz to 10Hz (Note 1)	1.5	2.5		1.5		pA _{p-p}	
Input Noise Current Density		f _O = 10Hz (Note 1)	0.03	0.07		0.03		pA/√Hz	
		f _O = 1000Hz	0.01			0.01			
Input Resistance	R _{IN}	Differential mode (Note 1)	0.8	2.0		0.6	2.0	GΩ	
		Common mode		12			12		
Input Voltage Range	V _{IN (CM)}	Upper limit	3.5	3.9		3.5	3.9	V	
		Lower limit	0	-0.3		0	-0.3		
Common-Mode Rejection Ratio	CMRR	V _{CM} = 0V to 3.5V	93	103		90	102	dB	
Power-Supply Rejection Ratio	PSRR	V _S = 2.2V to 12V	94	104		92	104	dB	
Large-Signal Voltage Gain	A _{VOL}	V _O = 0.03V to 4V, no load (Note 1)	140	700		110	700	V/mV	
		V _O = 0.03V to 3.5V, R _L = 50kΩ	80	200		70	200		

17μA Max, Dual/Quad, Single-Supply, Precision Op Amps

MAX478

ELECTRICAL CHARACTERISTICS: 5V (continued)

(V_S = 5V, 0V, V_{CM} = 0.1V, V_O = 1.4V, T_A = +25°C, unless otherwise noted.)

PARAMETER	SYMBOL	CONDITIONS	MAX478AC MAX479AC			MAX478C/E MAX479C/E			UNITS
			MIN	TYP	MAX	MIN	TYP	MAX	
Output Voltage Swing	V _{OUT}	Output low, no load	6.5	9.0		6.5	9.0		mV
		Output low, 2kΩ to GND	0.2	0.6		0.2	0.6		
		Output low, I _{SINK} = 100μA	120	160		120	160		
		Output high, no load	4.2	4.4		4.2	4.4		V
		Output high, 2kΩ to GND	3.5	3.8		3.5	3.8		
Slew Rate	SR	A _V = +1, C _L = 1pF (Note 1)	0.013	0.025		0.013	0.025		V/μs
Gain-Bandwidth Product	GBW	f _O ≤ 5kHz	60			60			kHz
Supply Current per Amplifier	I _S		13	18		14	21		μA
		V _S = ±1.5V, V _O = 0V	12	17		13	20		
Channel Separation		ΔV _{IN} = 3V, R _L = 10kΩ	130			130			dB
Minimum Supply Voltage	V _S	(Note 2)	2.0	2.2		2.0	2.2		V

ELECTRICAL CHARACTERISTICS: 5V

(V_S = 5V, 0V, V_{CM} = 0.1V, V_O = 1.4V, T_A = 0°C to +70°C, unless otherwise noted.)

PARAMETER	SYMBOL	CONDITIONS	MAX478AC MAX479AC			MAX478C MAX479C			UNITS
			MIN	TYP	MAX	MIN	TYP	MAX	
Input Offset Voltage	V _{OS}	MAX478ACP/CP	50	170		65	250		μV
		MAX479ACP/CP	60	200		70	290		
		MAX478CS				120	300		
		MAX479CS				130	400		
Input Offset Voltage Drift	$\frac{\Delta V_{OS}}{\Delta T}$	MAX47_ACP/CP (Note 1)	0.5	2.2		0.6	3.0		μV/°C
		MAX47_CS (Note 1)				0.8	4.5		
Input Offset Current	I _{OS}		0.06	0.35		0.06	0.50		nA
Input Bias Current	I _B		3	6		3	7		nA
Common-Mode Rejection Ratio	CMRR	V _{CM} = 0V to 3.4V	90	101		86	100		dB
Power-Supply Rejection Ratio	PSRR	V _S = 2.5V to 12V	90	102		88	102		dB
Large-Signal Voltage Gain	A _{VOL}	V _O = 0.05V to 4V, no load (Note 1)	105	500		80	500		V/mV
		V _O = 0.05V to 3.5V, R _L = 50kΩ	55	160		45	160		
Output Voltage Swing	V _{OUT}	Output low, no load	8	11		8	11		mV
		Output low, I _{SINK} = 100μA	140	190		140	190		
		Output high, no load	4.1	4.3		4.1	4.3		V
		Output high, 2kΩ to GND	3.3	3.8		3.3	3.8		
Supply Current per Amplifier	I _S		14	21		15	24		μA

17μA Max, Dual/Quad, Single-Supply, Precision Op Amps

ELECTRICAL CHARACTERISTICS: 5V

($V_S = 5V$, $0V$, $V_{CM} = 0.1V$, $V_O = 1.4V$, $T_A = -40^{\circ}C$ to $+85^{\circ}C$, unless otherwise noted.)

PARAMETER	SYMBOL	CONDITIONS	MAX478EP MAX479EP			MAX478ES MAX479ES			UNITS
			MIN	TYP	MAX	MIN	TYP	MAX	
Input Offset Voltage	V_{OS}	MAX478	80	315		150	400		μV
		MAX479	80	345		160	530		
Input Offset Voltage Drift	$\frac{\Delta V_{OS}}{\Delta T}$	(Note 1)	0.6	3.0		0.8	4.5		$\mu V/^{\circ}C$
Input Offset Current	I_{OS}		0.07	0.7		0.07	0.7		nA
Input Bias Current	I_B		4	8		4	8		nA
Common-Mode Rejection Ratio	CMRR	$V_{CM} = 0.05V$ to $3.2V$	84	98		84	98		dB
Power-Supply Rejection Ratio	PSRR	$V_S = 3.0V$ to $12V$	86	100		86	100		dB
Large-Signal Voltage Gain	A_{VOL}	$V_O = 0.05V$ to $4V$, no load (Note 1)	55	350		55	350		V/mV
		$V_O = 0.05V$ to $3.5V$, $R_L = 50k\Omega$	35	130		35	130		
Output Voltage Swing	V_{OUT}	Output low, no load	9	13		9	13		mV
		Output low, $I_{SINK} = 100\mu A$	160	220		160	220		
		Output high, no load	3.9	4.2		3.9	4.2		V
		Output high, $2k\Omega$ to GND	3.0	3.7		3.0	3.7		
Supply Current per Amplifier	I_S		15	27		15	27		μA

17μA Max, Dual/Quad, Single-Supply, Precision Op Amps

MAX478

ELECTRICAL CHARACTERISTICS: 3V

(V_S = 3V, 0V, V_{CM} = 0.1V, V_O = 0.8V, T_A = +25°C, unless otherwise noted.)

PARAMETER	SYMBOL	CONDITIONS	MAX478AC MAX479AC			MAX478C/E MAX479C/E			UNITS
			MIN	TYP	MAX	MIN	TYP	MAX	
Input Offset Voltage	V _{OS}	MAX478ACP/CP/EP		30	90		40	140	μV
		MAX479ACP/CP/EP		35	120		40	170	
		MAX478CS/ES					80	200	
		MAX479CS/ES					90	270	
Input Offset Current	I _{OS}			0.05			0.05		nA
Input Bias Current	I _B			3			3		nA
Input Noise Voltage	e _N	0.1Hz to 10Hz		1.0			1.0		μV _{p-p}
Input Voltage Range	V _{IN(CM)}	Upper limit	1.7	1.9		1.7	1.9		V
		Lower limit	0	-0.3		0	-0.3		
Common-Mode Rejection Ratio	CMRR	V _{CM} = 0V to 1.7V	93	103		90	102		dB
Power-Supply Rejection Ratio	PSRR	V _S = 2.2V to 12V	94	104		92	104		dB
Large-Signal Voltage Gain	A _{VOL}	V _O = 0.03V to 2V, no load (Note 1)	100	600		100	600		V/mV
		V _O = 0.03V to 1.5V, R _L = 50kΩ	30	180		30	180		
Output Voltage Swing	V _{OUT}	Output low, no load		6	9		6	9	mV
		Output low, 2kΩ to GND		0.2	0.6		0.2	0.6	
		Output high, no load	2.2	2.4		2.2	2.4		V
		Output high, 2kΩ to GND	1.8	2.0		1.8	2.0		
Gain-Bandwidth Product	GBW	f _O ≤ 5kHz		50			50		kHz
Supply Current per Amplifier	I _S			12	17		13	20	μA
Minimum Supply Voltage	V _S			2.2			2.2		V
		With 300μV V _{OS} degradation		1.7			1.7		

17 μ A Max, Dual/Quad, Single-Supply, Precision Op Amps

ELECTRICAL CHARACTERISTICS: ± 15 V

($V_S = \pm 15$ V, $T_A = +25^\circ\text{C}$, unless otherwise noted.)

PARAMETER	SYMBOL	CONDITIONS	MAX478AC MAX479AC			MAX478C/E MAX479C/E			UNITS
			MIN	TYP	MAX	MIN	TYP	MAX	
Input Offset Voltage	V_{OS}		80	350		100	480		μV
Input Offset Current	I_{OS}		0.05	0.25		0.05	0.35		nA
Input Bias Current	I_B		3	5		3	6		nA
Input Voltage Range	$V_{IN(CM)}$	Upper limit	13.5	13.9		13.5	13.9		V
		Lower limit	-15.0	-15.3		-15.0	-15.3		
Common-Mode Rejection Ratio	CMRR	$V_{CM} = +13.5\text{V}, -15\text{V}$	97	106		94	106		dB
Power-Supply Rejection Ratio	PSRR	$V_S = 5\text{V}, 0\text{V to } \pm 15\text{V}$	96	112		94	112		dB
Large-Signal Voltage Gain	A_{VOL}	$V_O = \pm 10\text{V}, R_L = 50\text{k}\Omega$	300	1200		250	1000		V/mV
		$V_O = \pm 10\text{V}, \text{no load}$	600	2500		400	2500		
Output Voltage Swing	V_{OUT}	$R_L = 50\text{k}\Omega$	± 13.0	± 14.2		± 13.0	± 14.2		V
		$R_L = 2\text{k}\Omega$	± 11.0	± 12.7		± 11.0	± 12.7		
Slew Rate	SR	$A_V = +1\text{V}, C_L = 15\text{pF}$	0.02	0.04		0.02	0.04		V/ μs
Gain-Bandwidth Product	GBW	$f_O \leq 5\text{kHz}$	85			85			kHz
Supply Current per Amplifier	I_S		16	21		17	25		μA

17μA Max, Dual/Quad, Single-Supply, Precision Op Amps

MAX478

ELECTRICAL CHARACTERISTICS: ±15V

(V_S = ±15V, T_A = 0°C to +70°C, unless otherwise noted.)

PARAMETER	SYMBOL	CONDITIONS	MAX478AC MAX479AC			MAX478C MAX479C			UNITS
			MIN	TYP	MAX	MIN	TYP	MAX	
Input Offset Voltage	V _{OS}		100	480		130	660		μV
Input Offset-Voltage Drift	$\frac{\Delta V_{OS}}{\Delta T}$	MAX47_ACP/CP (Note 1)	0.6	2.8		0.7	4.0		μV/°C
		MAX47_CS (Note 1)				0.9	5.5		
Input Offset Current	I _{OS}		0.06	0.35		0.06	0.35		nA
Input Bias Current	I _B		3	6		3	7		nA
Large-Signal Voltage Gain	A _{VOL}	V _O = ±10V, R _L = 50kΩ	200	800		150	750		V/mV
Common-Mode Rejection Ratio	CMRR	V _{CM} = +13V, -15V	94	104		91	104		dB
Power-Supply Rejection Ratio	PSRR	V _S = 5V, 0V to ±15V	93	110		91	110		dB
Output Voltage Swing	V _{OUT}	R _L = 5kΩ	±11.0	±13.5		±11.0	±13.5		V
Supply Current per Amplifier	I _S		17	24		18	28		μA

17μA Max, Dual/Quad, Single-Supply, Precision Op Amps

ELECTRICAL CHARACTERISTICS: ±15V

($V_S = \pm 15V$, $T_A = -40^\circ C$ to $+85^\circ C$, unless otherwise noted.)

PARAMETER	SYMBOL	CONDITIONS	MAX478EP MAX479EP			MAX478ES MAX479ES			UNITS
			MIN	TYP	MAX	MIN	TYP	MAX	
Input Offset Voltage	V_{OS}			130	740		130	740	μV
Input Offset-Voltage Drift	$\frac{\Delta V_{OS}}{\Delta T}$	(Note 1)		0.7	4.0		0.9	5.5	μV/°C
Input Offset Current	I_{OS}			0.07	0.70		0.07	0.70	nA
Input Bias Current	I_B			4	8		4	8	nA
Large-Signal Voltage Gain	A_{VOL}	$V_O = \pm 10V$, $R_L = 50k\Omega$	100	500		100	500		V/mV
Common-Mode Rejection Ratio	CMRR	$V_{CM} = +13V$, $-14.9V$	88	103		88	103		dB
Power-Supply Rejection Ratio	PSRR	$V_S = 5V$, $0V$ to $\pm 15V$	88	109		88	109		dB
Output Voltage Swing	V_{OUT}	$R_L = 5k\Omega$	±11.0	±13.5		±11.0	±13.5		V
Supply Current per Amplifier	I_S			19	30		19	30	μA

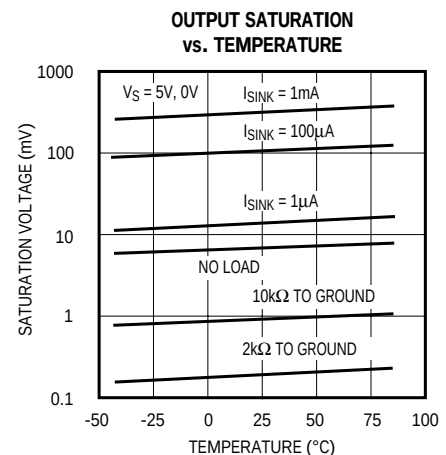
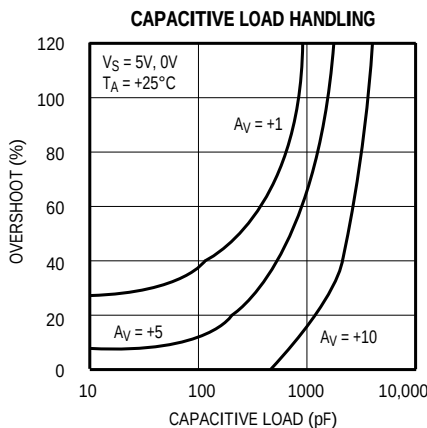
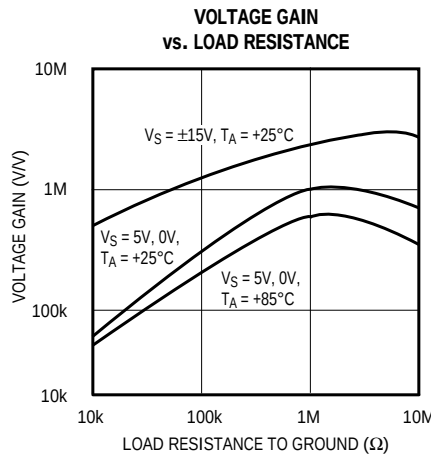
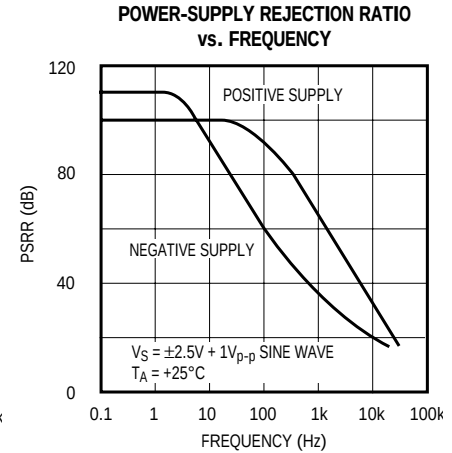
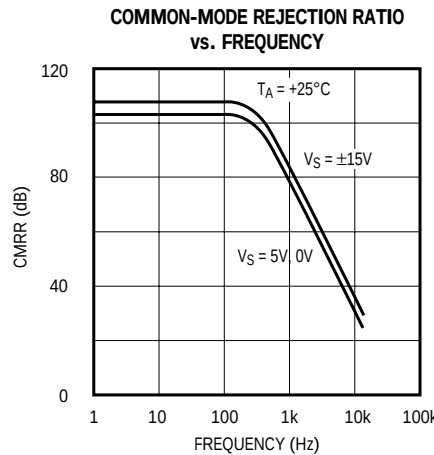
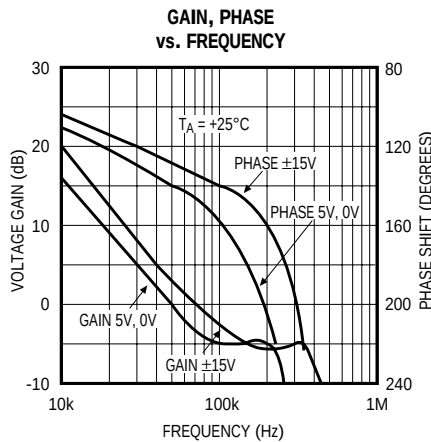
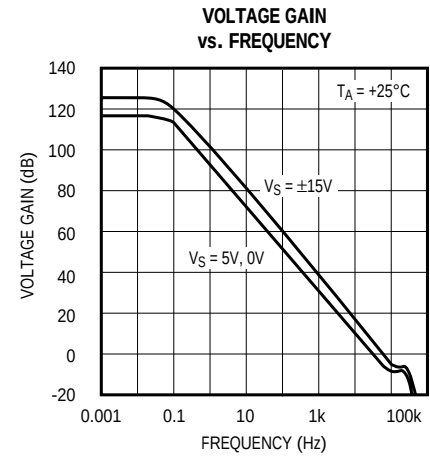
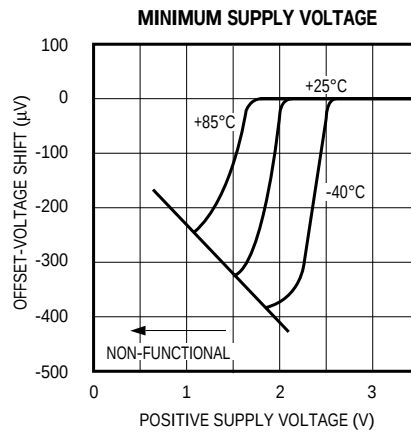
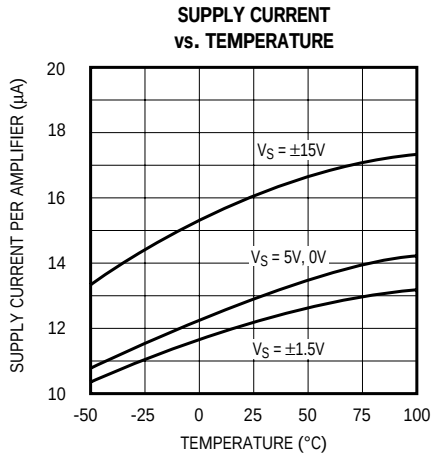
Note 1: Guaranteed by design.

Note 2: Power-supply rejection ratio is measured at the minimum supply voltage. The op amps actually work at 1.7V supply, but with additional input offset-voltage skew.

17 μ A Max, Dual/Quad, Single-Supply, Precision Op Amps

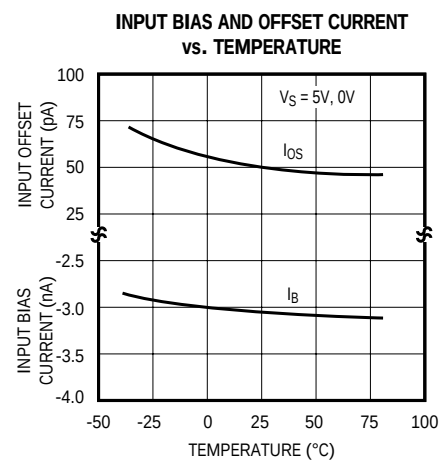
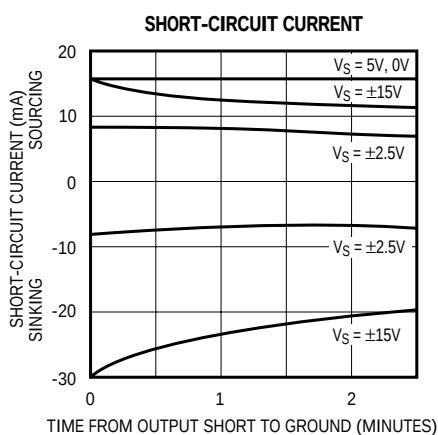
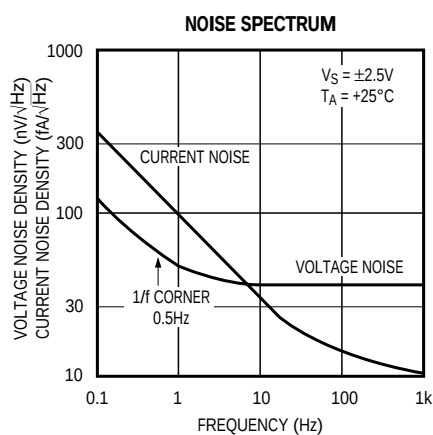
Typical Operating Characteristics

MAX478

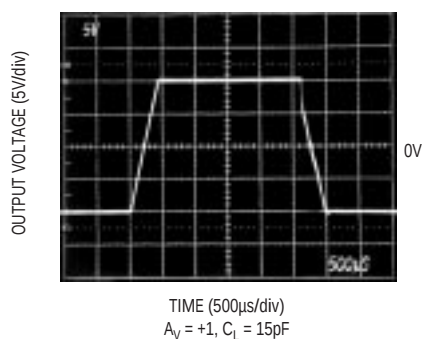


17 μ A Max, Dual/Quad, Single-Supply, Precision Op Amps

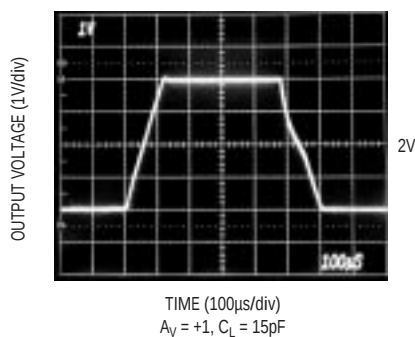
Typical Operating Characteristics (continued)



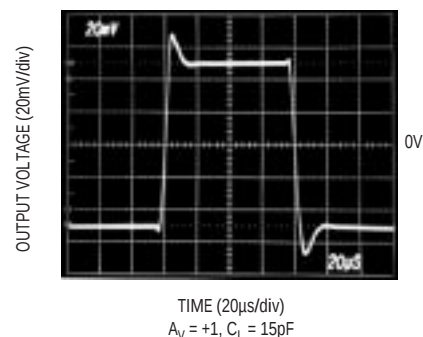
LARGE-SIGNAL TRANSIENT RESPONSE
 $V_S = \pm 15V$



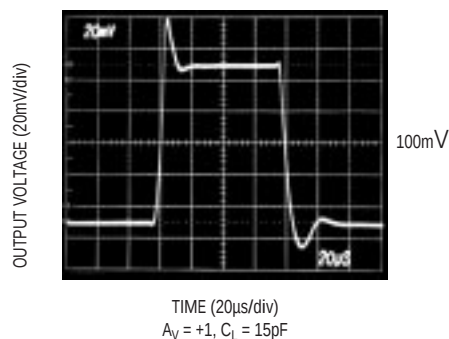
LARGE-SIGNAL TRANSIENT RESPONSE
 $V_S = 5V, 0V$



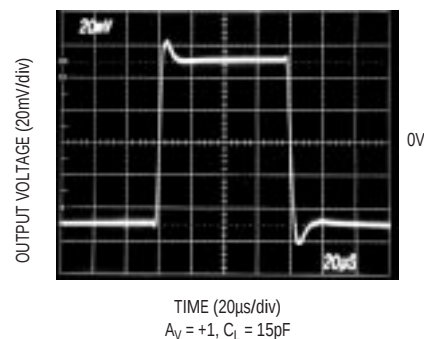
SMALL-SIGNAL TRANSIENT RESPONSE
 $V_S = \pm 2.5V$



SMALL-SIGNAL TRANSIENT RESPONSE
 $V_S = 5V, 0V$

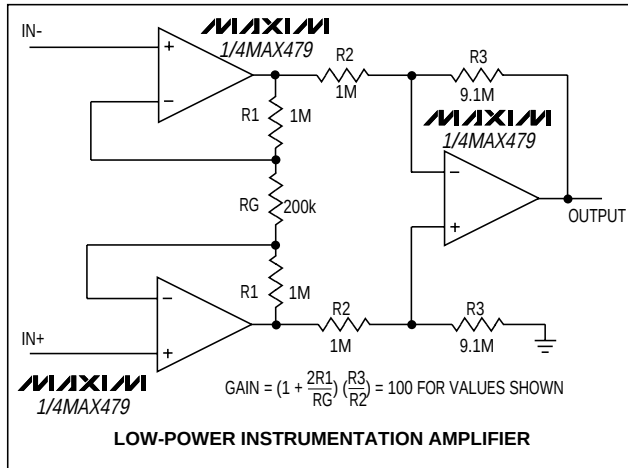


SMALL-SIGNAL TRANSIENT RESPONSE
 $V_S = \pm 15V$

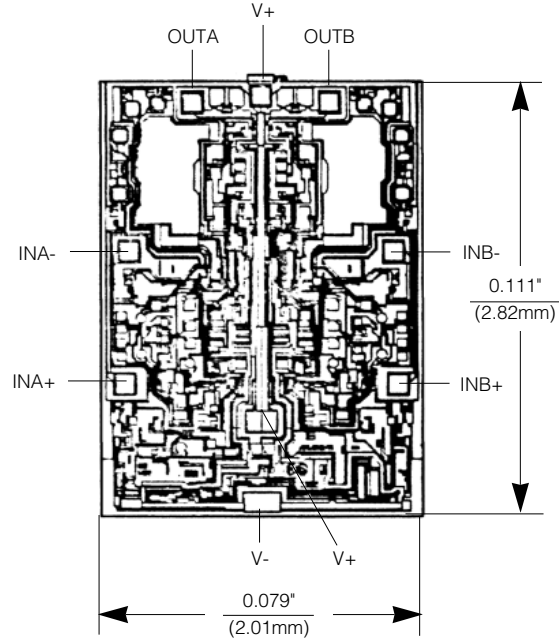


17μA Max, Dual/Quad, Single-Supply, Precision Op Amps

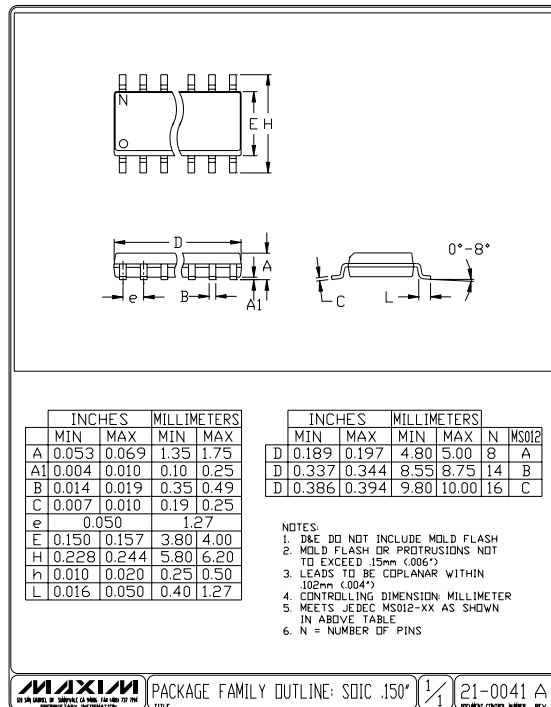
Typical Application Circuit



Chip Topography

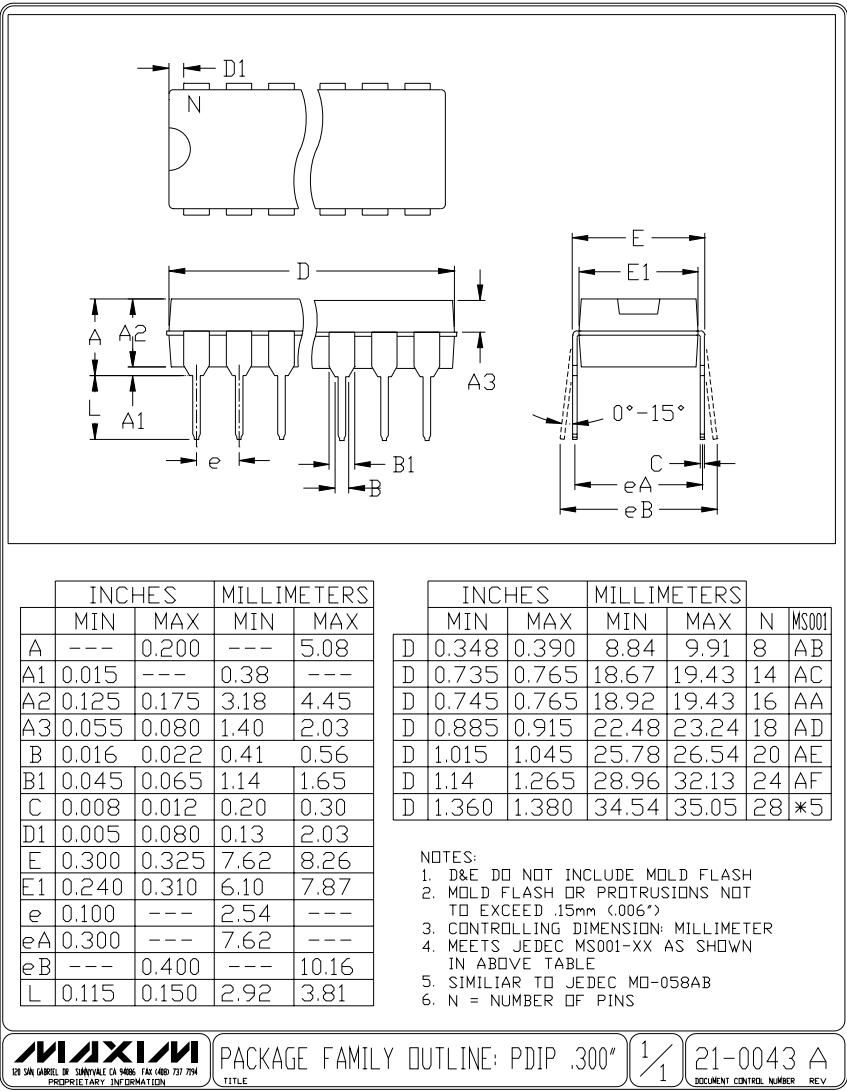


Package Information



17µA Max, Dual/Quad, Single-Supply,
Precision Op Amps

Package Information (continued)



Maxim cannot assume responsibility for use of any circuitry other than circuitry entirely embodied in a Maxim product. No circuitry or patent licenses are implied. Maxim reserves the right to change the circuitry and specifications without notice at any time.

12 Maxim Integrated Products, 120 San Gabriel Drive, Sunnyvale, CA 94086 408-737-7600